2SC1921

WWW.100Y.COM.T Silicon NPN Triple Diffused WWW.100Y

ITAC WWW.100Y.COM.TW

Application

High frequency high voltage amplifier
Video output W.1003

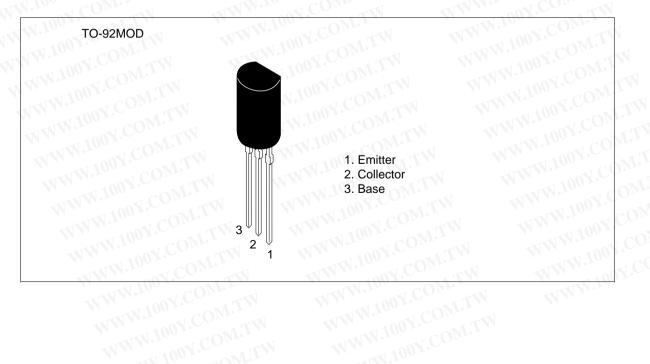
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Video output

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Outline





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Absolute Maximum Ratings ($Ta = 25^{\circ}C$)

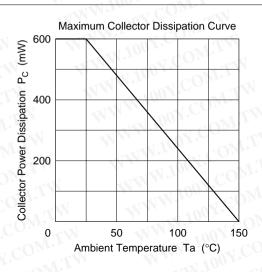
Item	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	250	V
Collector to emitter voltage	V_{CEO}	200	٧
Emitter to base voltage	V_{EBO}	5.100	V
Collector current	I _c	50	mA
Collector power dissipation	P _c	600	mW
Junction temperature	Y.CO. TjW	150	°C
Storage temperature	Tstg	-55 to +150	. °C
COMP	COMP	WWW.	1.COm

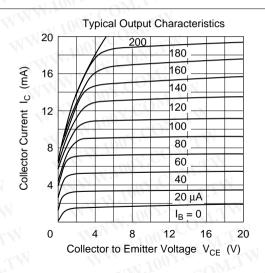
Electrical Characteristics (Ta = 25°C)

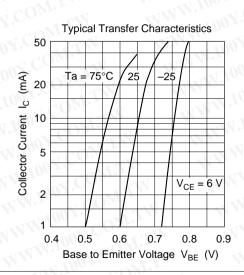
Item Collector to base breakdown	Symbol V _{(BR)CBO}	Min 250	Тур	Max —	Unit ∨	Test conditions $I_{C} = 10 \mu A, I_{E} = 0$
voltage		× 100	N	MIN		M. 1001. CON'.
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	200	OY.C	OM.TV	V	$I_{C} = 1 \text{ mA}, R_{BE} = \infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	5	100X.C	ON:	V	$I_{E} = 10 \mu A, I_{C} = 0$
Collector cutoff current	I _{CEO}	M	V TOOY	1.0	μΑ	V _{CE} = 120 V, R _{BE} = ∞
DC current transfer ratio	h _{FE}	30	1100	300	WILL	$V_{CE} = 6 \text{ V}, I_{C} = 10 \text{ mA}$
Collector to emitter saturation voltage	V _{CE(sat)}	WW	MM.100	1.0	V.TW	$I_C = 10 \text{ mA}, I_B = 1 \text{ mA}$
Gain bandwidth product	f _T	60	130	20 I.	MHz	$V_{CE} = 6 \text{ V}, I_{C} = 10 \text{ mA}$
Collector output capacitance	Cob	_ //	3	4	pF	$V_{CB} = 6 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$

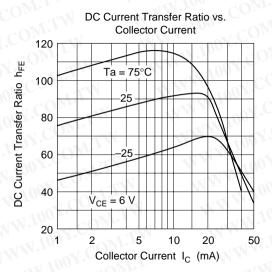
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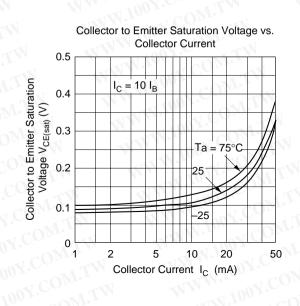


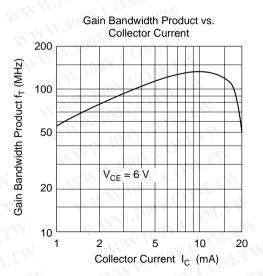


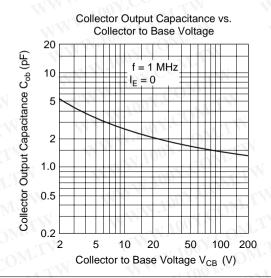




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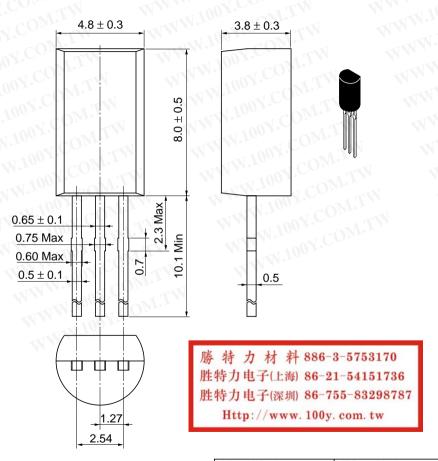






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Unit: mm



Hitachi Code	TO-92 Mod
JEDEC	
EIAJ	Conforms
Weight (reference value)	0.35 g

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